L Number	Hits	Search Text	DB	Time stamp
13	18	active and (semiconductor near laser) and (temperature near control) and ((multi$4 near quantum near well) or mqw) and (crystal near layer)	USPAT; US-PGPUB	2003/04/17 08:53
16	11	active and (semiconductor near laser) and (temperature near control) and ((multi$4 near quantum near well) or mqw) and (crystal near layer)	USPAT	2003/04/17 09:02
17	2	(semiconductor near laser) and (active same (temperature near control)) and ((multi$4 near quantum near well) or mqw) and (crystal near layer)	USPAT	2003/04/17 09:02
18	3	(semiconductor near laser) and (active same ((temperature or thermal) near control)) and ((multi$4 near quantum near well) or mqw) and (crystal near layer)	USPAT	2003/04/17 09:04
19	12	active and (semiconductor near laser) and ((temperature or thermal) near control) and ((multi$4 near quantum near well) or mqw) and (crystal near layer)	USPAT	2003/04/17 09:03
20	18	(semiconductor near laser) and (active same ((temperature or thermal) near control)) and ((multi$4 near quantum near well) or mqw)	USPAT	2003/04/17 09:22
21	1	("5,694,503").PN.	USPAT; US-PGPUB	2003/04/17 09:22
-	10	(("5978535") or ("4803689") or ("5960142") or ("6155724") or ("6219364") or ("5706302") or ("6252726") or ("6021141") or ("5875204") or ("4399541")).PN.	USPAT	2002/09/23 08:20
-	49	((active near (region or film or medium or layer)) and (temperature near control) and (optical near modulat$5)) and (semiconductor near laser)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/23 08:38
-	69	(active near (region or film or medium or layer)) and (temperature near control) and (optical near modulat$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/23 08:37
-	0	((active near (region or film or medium or layer)) and (temperature near control) and (optical near modulat$5)) and ((("5978535") or ("4803689") or ("5960142") or ("6155724") or ("6219364") or ("5706302") or ("6252726") or ("6021141") or ("5875204") or ("4399541")).PN.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/23 08:36
-	365	(active near (region or film or medium or layer)) and (temperature near control) and (modulat$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/23 16:34
-	143	((active near (region or film or medium or layer)) and (temperature near control) and (modulat$5)) and (semiconductor near laser)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/23 08:38
-	101	((active near (region or film or medium or layer)) or mqw or (milti$6 near quantum or well)) and (temperature near control) and (modulat$5) and crystal near layer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/23 16:53

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